



# STGP10NC60KD - STGF10NC60KD STGB10NC60KD

N-CHANNEL 10A - 600V - TO-220/TO-220FP/D<sup>2</sup>PAK  
SHORT CIRCUIT RATED PowerMESH™ IGBT

**Table 1: General Features**

| TYPE         | V <sub>CES</sub> | V <sub>CE(sat)</sub> (Max)<br>@25°C | I <sub>C</sub><br>@100°C |
|--------------|------------------|-------------------------------------|--------------------------|
| STGB10NC60KD | 600 V            | < 2.5 V                             | 10 A                     |
| STGF10NC60KD | 600 V            | < 2.5 V                             | 6 A                      |
| STGP10NC60KD | 600 V            | < 2.5 V                             | 10 A                     |

- LOWER ON-VOLTAGE DROP (V<sub>cesat</sub>)
- OFF LOSSES INCLUDE TAIL CURRENT
- LOWER C<sub>RES</sub> / C<sub>IES</sub> RATIO
- SWITCHING LOSSES INCLUDE DIODE RECOVERY ENERGY
- VERY SOFT ULTRA FAST RECOVERY ANTI PARALLEL DIODE
- NEW GENERATION PRODUCTS WITH TIGHTER PARAMETER DISTRIBUTION

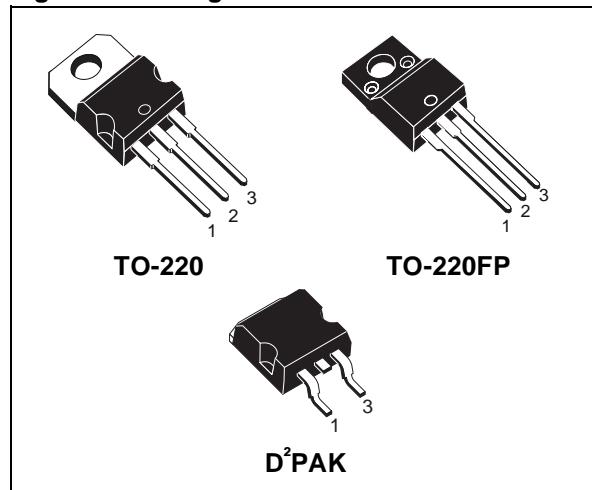
## DESCRIPTION

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performances. The suffix "K" identifies a family optimized for high frequency motor control applications with short circuit withstand capability.

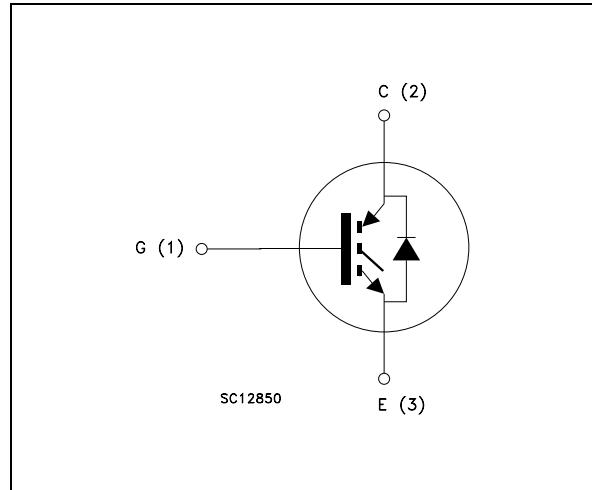
## APPLICATIONS

- HIGH FREQUENCY MOTOR CONTROLS
- SMPS and PFC IN BOTH HARD SWITCH AND RESONANT TOPOLOGIES
- MOTOR DRIVERS

**Figure 1: Package**



**Figure 2: Internal Schematic Diagram**



**Table 2: Order Codes**

| SALES TYPE     | MARKING    | PACKAGE            | PACKAGING   |
|----------------|------------|--------------------|-------------|
| STGB10NC60KDT4 | GB10NC60KD | D <sup>2</sup> PAK | TAPE & REEL |
| STGF10NC60KD   | GF10NC60KD | TO-220FP           | TUBE        |
| STGP10NC60KD   | GP10NC60KD | TO-220             | TUBE        |

**Table 3: Absolute Maximum ratings**

| Symbol       | Parameter   | Value                        |              | Unit                |
|--------------|---|------------------------------|--------------|---------------------|
|              |   | STGB10NC60KD<br>STGP10NC60KD | STGF10NC60KD |                     |
| $V_{CES}$    | Collector-Emitter Voltage ( $V_{GS} = 0$ )                                  | 600                          |              | V                   |
| $V_{ECR}$    | Emitter-Collector Voltage   | 20                           |              | V                   |
| $V_{GE}$     | Gate-Emitter Voltage  | $\pm 20$                     |              | V                   |
| $I_c$        | Collector Current (continuous) at $T_C = 25^\circ\text{C}$ (#)              | 20                           | 9            | A                   |
| $I_c$        | Collector Current (continuous) at $T_C = 100^\circ\text{C}$ (#)             | 10                           | 6            | A                   |
| $I_{CM}$ (■) | Collector Current (pulsed)  | 40                           |              | A                   |
| $I_F$        | Diode RMS Forward Current at $T_C = 25^\circ\text{C}$                       | 10                           |              | A                   |
| $P_{TOT}$    | Total Dissipation at $T_C = 25^\circ\text{C}$                               | 60                           | 25           | W                   |
|              | Derating Factor   | 0.48                         | 0.20         | W/ $^\circ\text{C}$ |
| $V_{ISO}$    | Insulation Withstand Voltage A.C. ( $t = 1$ sec; $T_C = 25^\circ\text{C}$ ) | --                           | 2500         | V                   |
| $T_{stg}$    | Storage Temperature   | – 55 to 150                  |              | $^\circ\text{C}$    |
| $T_j$        | Operating Junction Temperature  |                              |              |                     |

(■) Pulse width limited by max. junction temperature.

**Table 4: Thermal Data**

|                |  |                         | Min. | Typ. | Max. |                    |
|----------------|--|-------------------------|------|------|------|--------------------|
| $R_{thj-case}$ | Thermal Resistance Junction-case   | <b>TO-220<br/>D2PAK</b> |      |      | 2.08 | $^\circ\text{C/W}$ |
|                |  | <b>TO-220FP</b>         |      |      | 5.0  | $^\circ\text{C/W}$ |
| $R_{thj-amb}$  | Thermal Resistance Junction-ambient  |                         |      |      | 62.5 | $^\circ\text{C/W}$ |
| $T_L$          | Maximum Lead Temperature for Soldering Purpose (1.6 mm from case, for 10 sec.) |                         |      | 300  |      | $^\circ\text{C}$   |

### ELECTRICAL CHARACTERISTICS ( $T_{CASE} = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED)

**Table 5: Main Parameters**

| Symbol        | Parameter                                     | Test Conditions   | Min. | Typ.     | Max.      | Unit                |
|---------------|---|---|------|----------|-----------|---------------------|
| $V_{BR(CES)}$ | Collector-Emitter Breakdown Voltage           | $I_C = 1$ mA, $V_{GE} = 0$  | 600  |          |           | V                   |
| $I_{CES}$     | Collector cut-off Current ( $V_{GE} = 0$ )    | $V_{CE} = \text{Max Rating}$ ,<br>$T_C = 25^\circ\text{C}$<br>$V_{CE} = \text{Max Rating}$ ,<br>$T_C = 125^\circ\text{C}$ |      |          | 10<br>1   | $\mu\text{A}$<br>mA |
| $I_{GES}$     | Gate-Emitter Leakage Current ( $V_{CE} = 0$ ) | $V_{GE} = \pm 20\text{V}$ , $V_{CE} = 0$  |      |          | $\pm 100$ | nA                  |
| $V_{GE(th)}$  | Gate Threshold Voltage                        | $V_{CE} = V_{GE}$ , $I_C = 250$ $\mu\text{A}$   | 5    |          | 7         | V                   |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage          | $V_{GE} = 15\text{V}$ , $I_C = 5\text{A}$<br>$V_{GE} = 15\text{V}$ , $I_C = 5\text{A}$ ,<br>$T_C = 125^\circ\text{C}$     |      | 2<br>1.8 | 2.5       | V<br>V              |

(#) Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{JMAX} - T_C}{R_{THJ-C} \times V_{CESAT(MAX)}(T_C, I_C)}$$

**ELECTRICAL CHARACTERISTICS (CONTINUED)****Table 6: Dynamic**

| Symbol                              | Parameter   | Test Conditions   | Min. | Typ.             | Max. | Unit           |
|-------------------------------------|---|---|------|------------------|------|----------------|
| $g_{fs}(1)$                         | Forward Transconductance  | $V_{CE} = 15 \text{ V}$ , $I_C = 5 \text{ A}$   |      | 15               |      | S              |
| $C_{ies}$<br>$C_{oes}$<br>$C_{res}$ | Input Capacitance<br>Output Capacitance<br>Reverse Transfer Capacitance | $V_{CE} = 25 \text{ V}$ , $f = 1 \text{ MHz}$ , $V_{GE} = 0$  |      | 380<br>46<br>8.5 |      | pF<br>pF<br>pF |
| $Q_g$<br>$Q_{ge}$<br>$Q_{gc}$       | Total Gate Charge<br>Gate-Emitter Charge<br>Gate-Collector Charge       | $V_{CE} = 390 \text{ V}$ , $I_C = 5 \text{ A}$ ,<br>$V_{GE} = 15 \text{ V}$ ,<br>(see Figure 20)              |      | 19<br>5<br>9     |      | nC<br>nC<br>nC |
| $t_{scw}$                           | Short Circuit Withstand Time  | $V_{CE} = 0.5 \text{ V}_{BR(CES)}$ , $T_j = 125^\circ\text{C}$<br>$R_G = 10 \Omega$ , $V_{GE} = 12 \text{ V}$ | 10   |                  |      | μs             |

**Table 7: Switching On**

| Symbol  | Parameter  | Test Conditions  | Min. | Typ.               | Max. | Unit             |
|---|--|--|------|--------------------|------|------------------|
| $t_{d(on)}$<br>$t_r$<br>( $di/dt$ ) <sub>on</sub> | Turn-on Delay Time<br>Current Rise Time<br>Turn-on Current Slope | $V_{CC} = 390 \text{ V}$ , $I_C = 5 \text{ A}$<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$ , $T_j = 25^\circ\text{C}$<br>(see Figure 18)  |      | 17<br>6<br>655     |      | ns<br>ns<br>A/μs |
| $t_{d(on)}$<br>$t_r$<br>( $di/dt$ ) <sub>on</sub> | Turn-on Delay Time<br>Current Rise Time<br>Turn-on Current Slope | $V_{CC} = 390 \text{ V}$ , $I_C = 5 \text{ A}$<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$ , $T_j = 125^\circ\text{C}$<br>(see Figure 18) |      | 16.5<br>6.5<br>575 |      | ns<br>ns<br>A/μs |

**Table 8: Switching Off**

| Symbol                                | Parameter   | Test Conditions   | Min. | Typ.             | Max. | Unit           |
|---------------------------------------|---|---|------|------------------|------|----------------|
| $t_r(V_{off})$<br>$t_d(off)$<br>$t_f$ | Off Voltage Rise Time<br>Turn-off Delay Time<br>Current Fall Time | $V_{CC} = 390 \text{ V}$ , $I_C = 5 \text{ A}$ ,<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$<br>$T_j = 25^\circ\text{C}$<br>(see Figure 18)  |      | 33<br>72<br>82   |      | ns<br>ns<br>ns |
| $t_r(V_{off})$<br>$t_d(off)$<br>$t_f$ | Off Voltage Rise Time<br>Turn-off Delay Time<br>Current Fall Time | $V_{CC} = 390 \text{ V}$ , $I_C = 5 \text{ A}$ ,<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$<br>$T_j = 125^\circ\text{C}$<br>(see Figure 18) |      | 60<br>106<br>136 |      | ns<br>ns<br>ns |

**Table 9: Switching Energy**

| Symbol                                  | Parameter   | Test Conditions  | Min. | Typ.             | Max. | Unit           |
|---|---|--|------|------------------|------|----------------|
| $E_{on}(2)$<br>$E_{off}(3)$<br>$E_{ts}$ | Turn-on Switching Losses<br>Turn-off Switching Losses<br>Total Switching Losses | $V_{CC} = 390 \text{ V}$ , $I_C = 75 \text{ A}$<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$ , $T_j = 25^\circ\text{C}$<br>(see Figure 18) |      | 55<br>85<br>140  |      | μJ<br>μJ<br>μJ |
| $E_{on}(2)$<br>$E_{off}(3)$<br>$E_{ts}$ | Turn-on Switching Losses<br>Turn-off Switching Losses<br>Total Switching Losses | $V_{CC} = 390 \text{ V}$ , $I_C = 5 \text{ A}$<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$ , $T_j = 125^\circ\text{C}$<br>(see Figure 18) |      | 87<br>162<br>249 |      | μJ<br>μJ<br>μJ |

(1) Pulsed: Pulse duration = 300 μs, duty cycle 1.5%

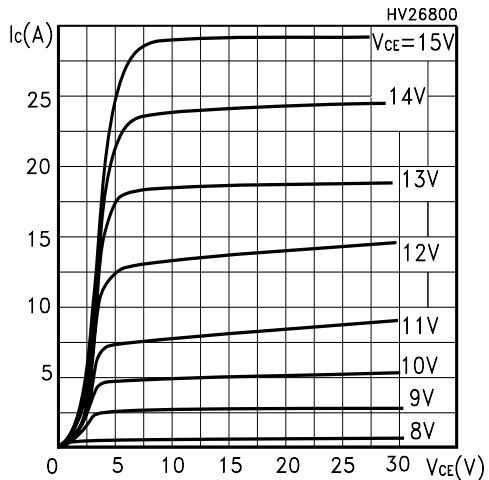
(2) Eon is the turn-on losses when a typical diode is used in the test circuit in figure 2. If the IGBT is offered in a package with a co-pack diode, the co-pack diode is used as external diode. IGBTs &amp; DIODE are at the same temperature (25°C and 125°C)

(3) Turn-off losses include also the tail of the collector current.

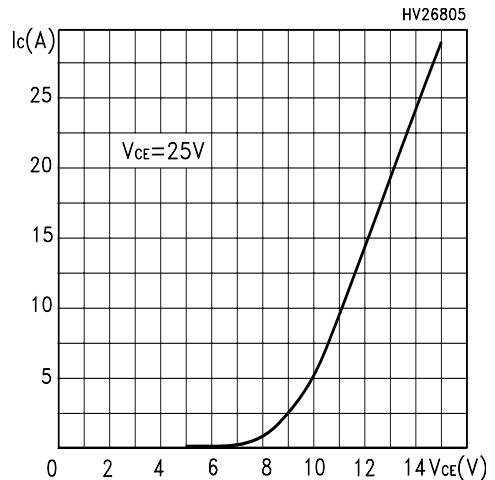
**Table 10: Collector-Emitter Diode**

| Symbol                            | Parameter  | Test Conditions  | Min. | Typ.                | Max. | Unit          |
|-----------------------------------|--|--|------|---------------------|------|---------------|
| $V_f$                             | Forward On-Voltage   | $I_f = 2.5 \text{ A}$<br>$I_f = 2.5 \text{ A}, T_j = 125 \text{ }^\circ\text{C}$   |      | 1.6<br>1.3          | 2.1  | V<br>V        |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{rrm}$ | Reverse Recovery Time<br>Reverse Recovery Charge<br>Reverse Recovery Current | $I_f = 5 \text{ A}, V_R = 30 \text{ V},$<br>$T_j = 25^\circ\text{C}, di/dt = 100 \text{ A}/\mu\text{s}$<br>(see Figure 6)  |      | 23.5<br>16.5<br>1.4 |      | ns<br>nC<br>A |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{rrm}$ | Reverse Recovery Time<br>Reverse Recovery Charge<br>Reverse Recovery Current | $I_f = 5 \text{ A}, V_R = 30 \text{ V},$<br>$T_j = 125^\circ\text{C}, di/dt = 100 \text{ A}/\mu\text{s}$<br>(see Figure 6) |      | 39<br>39<br>2       |      | ns<br>nC<br>A |

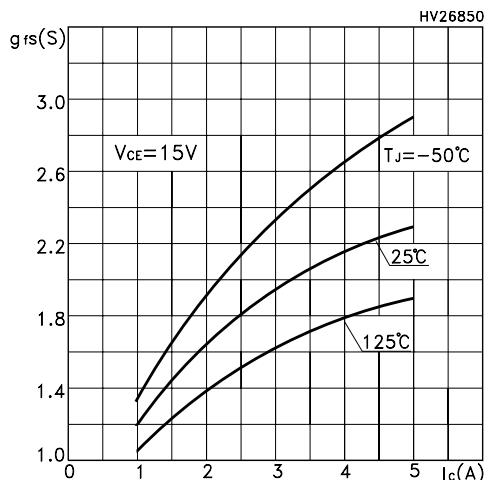
**Figure 3: Output Characteristics**



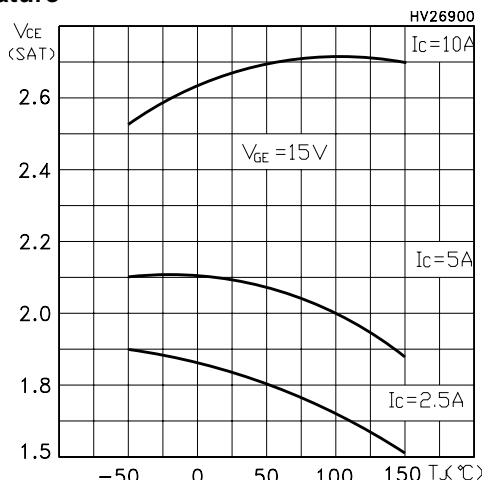
**Figure 6: Transfer Characteristics**



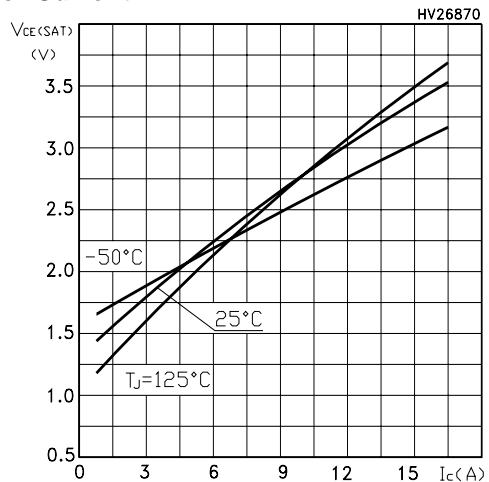
**Figure 4: Transconductance**



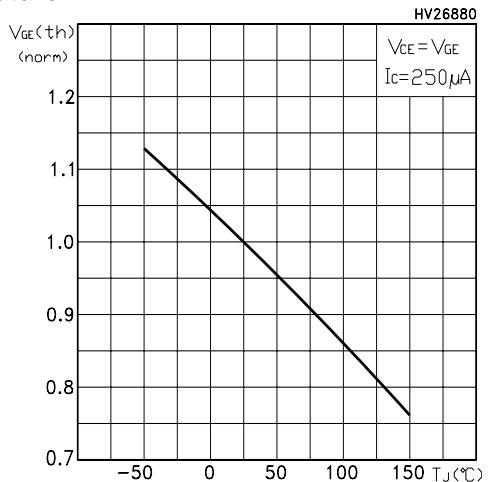
**Figure 7: Collector-Emitter On Voltage vs Temperature**



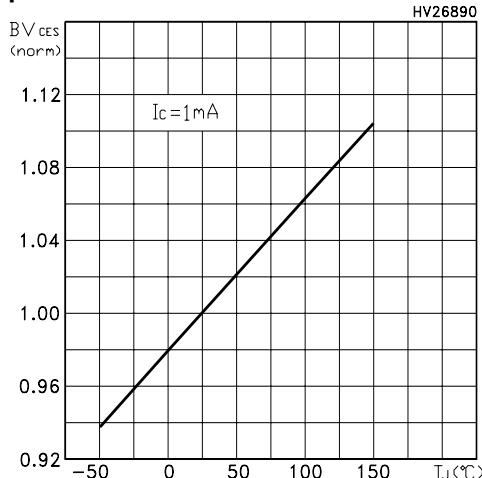
**Figure 5: Collector-Emitter On Voltage vs Collector Current**



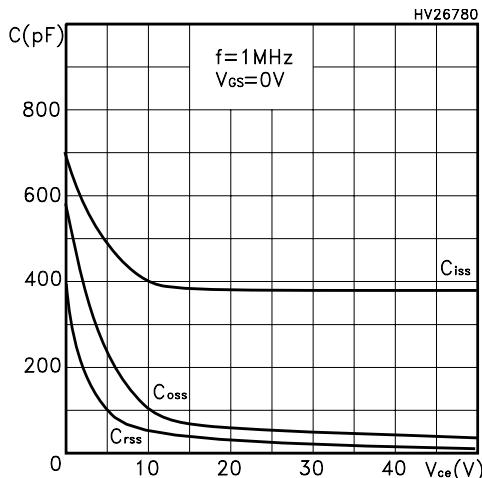
**Figure 8: Normalized Gate Threshold vs Temperature**



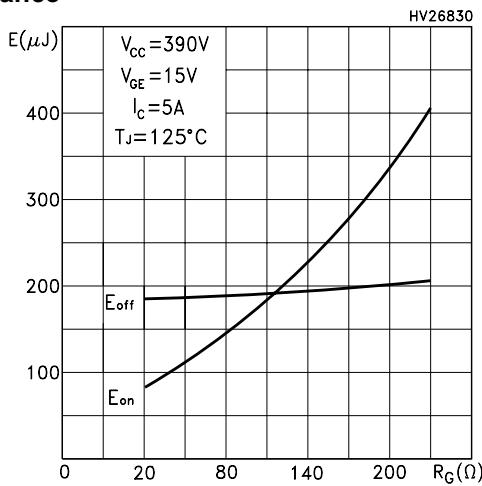
**Figure 9: Normalized Breakdown Voltage vs Temperature**



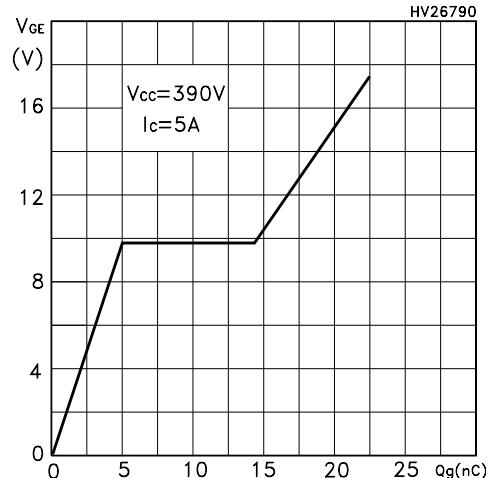
**Figure 10: Capacitance Variations**



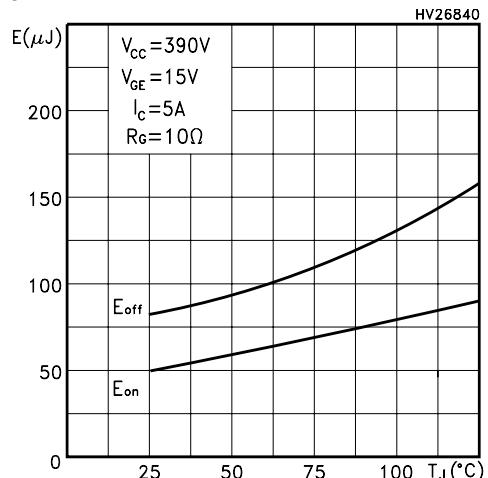
**Figure 11: Total Switching Losses vs Gate Resistance**



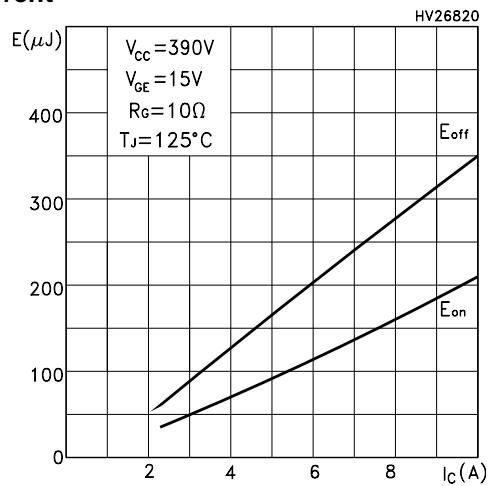
**Figure 12: Gate Charge vs Gate-Emitter Voltage**



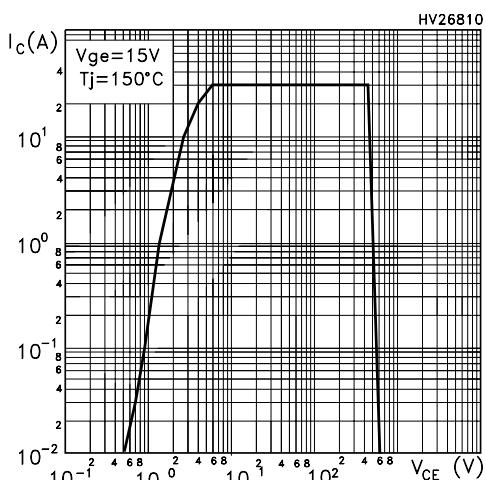
**Figure 13: Total Switching Losses vs Temperature**



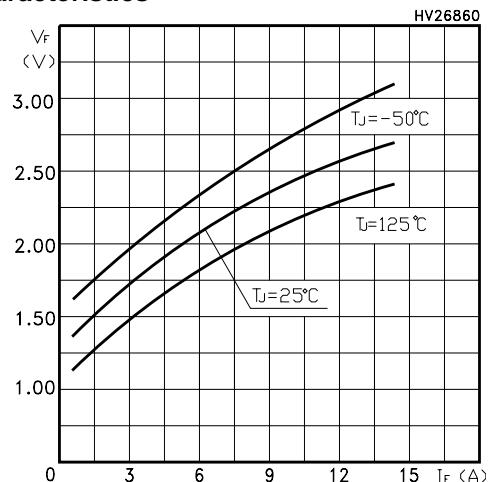
**Figure 14: Total Switching Losses vs Collector Current**



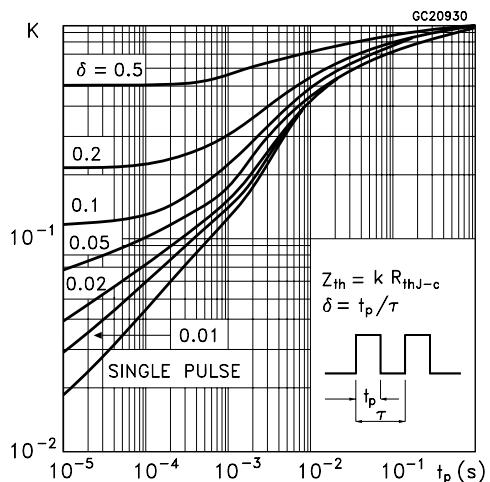
**Figure 15: Turn-Off SOA**



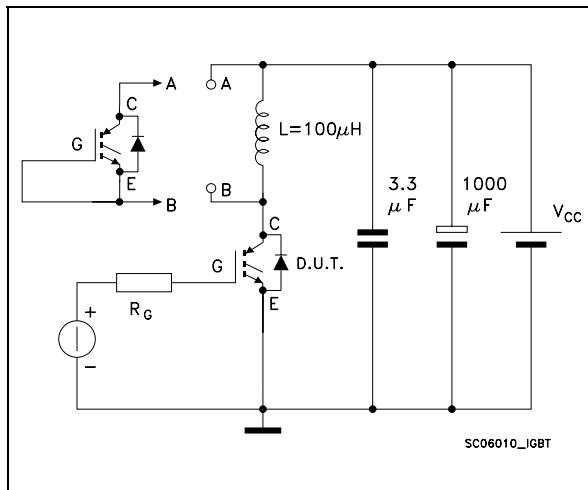
**Figure 17: Emitter-Collector Diode Characteristics**



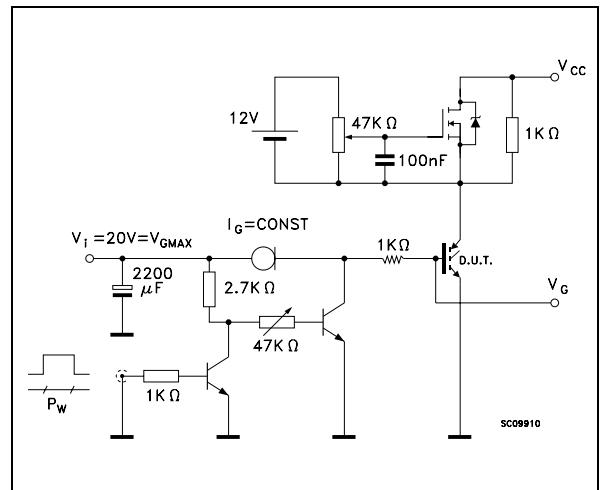
**Figure 16: Thermal Impedance**



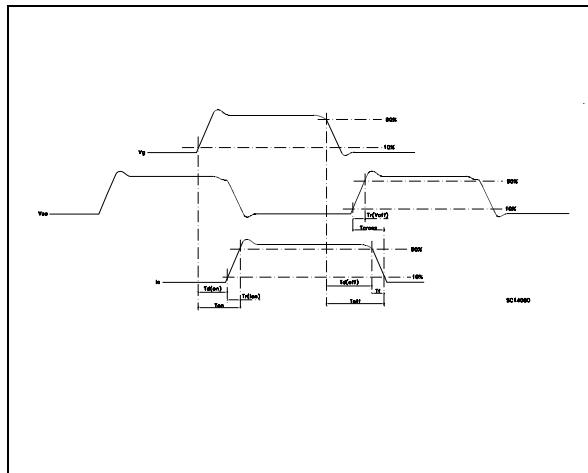
**Figure 18: Test Circuit for Inductive Load Switching**



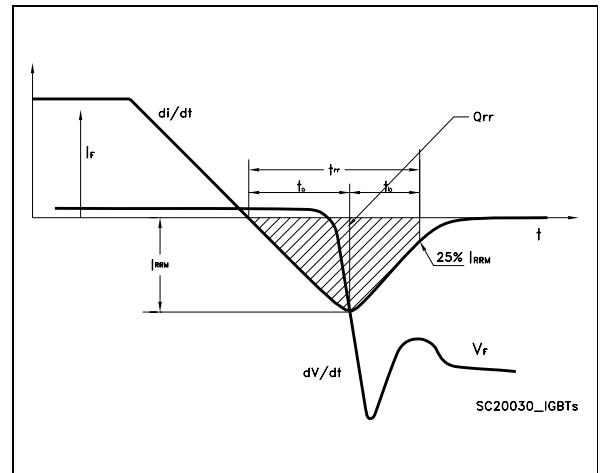
**Figure 20: Gate Charge Test Circuit**



**Figure 19: Switching Waveforms**

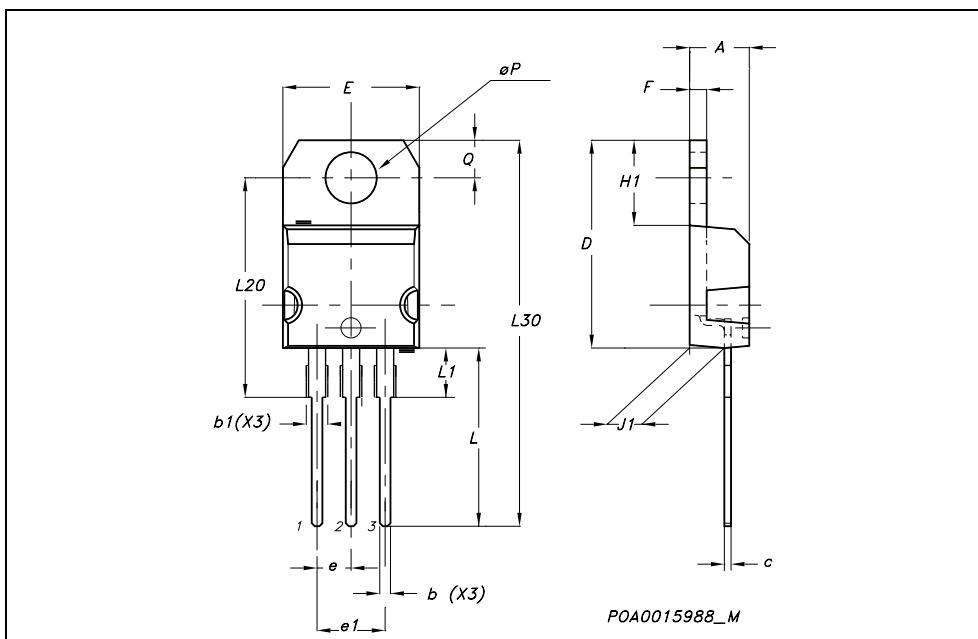


**Figure 21: Diode Recovery Times Waveform**



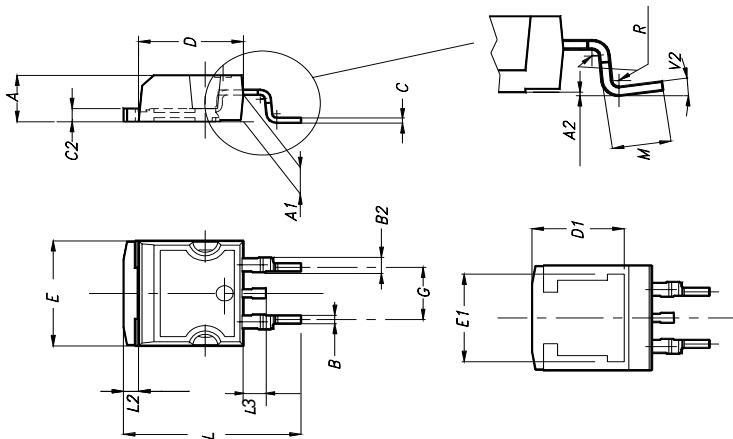
## TO-220 MECHANICAL DATA

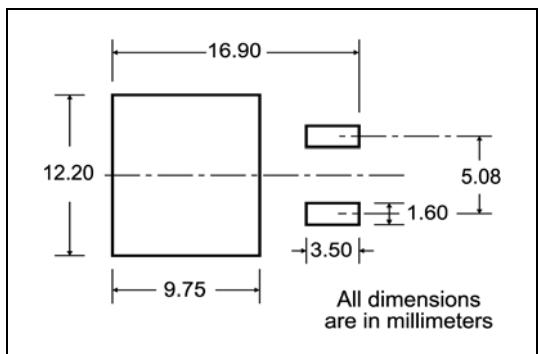
| DIM.     | mm.   |       |       | inch  |       |       |
|----------|-------|-------|-------|-------|-------|-------|
|          | MIN.  | TYP.  | MAX.  | MIN.  | TYP.  | MAX.  |
| A        | 4.40  |       | 4.60  | 0.173 |       | 0.181 |
| b        | 0.61  |       | 0.88  | 0.024 |       | 0.034 |
| b1       | 1.15  |       | 1.70  | 0.045 |       | 0.066 |
| c        | 0.49  |       | 0.70  | 0.019 |       | 0.027 |
| D        | 15.25 |       | 15.75 | 0.60  |       | 0.620 |
| E        | 10    |       | 10.40 | 0.393 |       | 0.409 |
| e        | 2.40  |       | 2.70  | 0.094 |       | 0.106 |
| e1       | 4.95  |       | 5.15  | 0.194 |       | 0.202 |
| F        | 1.23  |       | 1.32  | 0.048 |       | 0.052 |
| H1       | 6.20  |       | 6.60  | 0.244 |       | 0.256 |
| J1       | 2.40  |       | 2.72  | 0.094 |       | 0.107 |
| L        | 13    |       | 14    | 0.511 |       | 0.551 |
| L1       | 3.50  |       | 3.93  | 0.137 |       | 0.154 |
| L20      |       | 16.40 |       |       | 0.645 |       |
| L30      |       | 28.90 |       |       | 1.137 |       |
| $\phi P$ | 3.75  |       | 3.85  | 0.147 |       | 0.151 |
| Q        | 2.65  |       | 2.95  | 0.104 |       | 0.116 |



**D<sup>2</sup>PAK MECHANICAL DATA**

| DIM. | mm.  |     |       | inch  |       |       |
|------|------|-----|-------|-------|-------|-------|
|      | MIN. | TYP | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |     | 4.6   | 0.173 |       | 0.181 |
| A1   | 2.49 |     | 2.69  | 0.098 |       | 0.106 |
| A2   | 0.03 |     | 0.23  | 0.001 |       | 0.009 |
| B    | 0.7  |     | 0.93  | 0.027 |       | 0.036 |
| B2   | 1.14 |     | 1.7   | 0.044 |       | 0.067 |
| C    | 0.45 |     | 0.6   | 0.017 |       | 0.023 |
| C2   | 1.23 |     | 1.36  | 0.048 |       | 0.053 |
| D    | 8.95 |     | 9.35  | 0.352 |       | 0.368 |
| D1   |      | 8   |       |       | 0.315 |       |
| E    | 10   |     | 10.4  | 0.393 |       |       |
| E1   |      | 8.5 |       |       | 0.334 |       |
| G    | 4.88 |     | 5.28  | 0.192 |       | 0.208 |
| L    | 15   |     | 15.85 | 0.590 |       | 0.625 |
| L2   | 1.27 |     | 1.4   | 0.050 |       | 0.055 |
| L3   | 1.4  |     | 1.75  | 0.055 |       | 0.068 |
| M    | 2.4  |     | 3.2   | 0.094 |       | 0.126 |
| R    |      | 0.4 |       |       | 0.015 |       |
| V2   | 0°   |     | 4°    |       |       |       |



**D<sup>2</sup>PAK FOOTPRINT****TAPE AND REEL SHIPMENT**

| TAPE MECHANICAL DATA |      |      |        | REEL MECHANICAL DATA |      |      |      |        |      |
|----------------------|------|------|--------|----------------------|------|------|------|--------|------|
| DIM.                 | mm   |      | inch   |                      | DIM. | mm   |      | inch   |      |
|                      | MIN. | MAX. | MIN.   | MAX.                 |      | MIN. | MAX. | MIN.   | MAX. |
| A0                   | 10.5 | 10.7 | 0.413  | 0.421                | A    | 330  |      | 12.992 |      |
| B0                   | 15.7 | 15.9 | 0.618  | 0.626                | B    | 1.5  |      | 0.059  |      |
| D                    | 1.5  | 1.6  | 0.059  | 0.063                | C    | 12.8 | 13.2 | 0.504  |      |
| D1                   | 1.59 | 1.61 | 0.062  | 0.063                | G    | 24.4 | 26.4 | 0.960  |      |
| E                    | 1.65 | 1.85 | 0.065  | 0.073                | N    | 100  |      | 3.937  |      |
| F                    | 11.4 | 11.6 | 0.449  | 0.456                | T    |      | 30.4 | 1.197  |      |
| K0                   | 4.8  | 5.0  | 0.189  | 0.197                |      |      |      |        |      |
| P0                   | 3.9  | 4.1  | 0.153  | 0.161                |      |      |      |        |      |
| P1                   | 11.9 | 12.1 | 0.468  | 0.476                |      |      |      |        |      |
| P2                   | 1.9  | 2.1  | 0.075  | 0.082                |      |      |      |        |      |
| R                    | 50   |      | 1.574  |                      |      |      |      |        |      |
| T                    | 0.25 | 0.35 | 0.0098 | 0.0137               |      |      |      |        |      |
| W                    | 23.7 | 24.3 | 0.933  | 0.956                |      |      |      |        |      |

**TAPE MECHANICAL DATA**

40 mm min. Access hole at slot location  
Full radius  
Tape slot in core for tape start 2.5mm min. width

**REEL MECHANICAL DATA**

Base QTY      Bulk QTY  
1000      1000

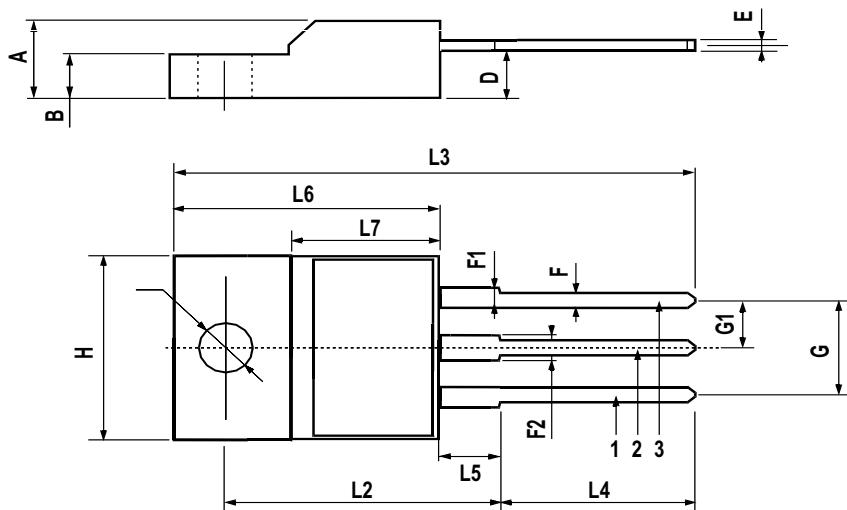
TOP COVER TAPE  
User Direction of Feed  
FEED DIRECTION  
Bending radius R min.

The detailed diagrams show the reel assembly. The reel has a top cover tape labeled K0. The user direction of feed is indicated by an arrow pointing to the left. The feed direction is indicated by an arrow pointing to the right. The bending radius is labeled R min. The diagram also shows the center line of cavity, pitch dimensions P1 through P6, and various dimensions A0 through W.

\* on sales type

## TO-220FP MECHANICAL DATA

| DIM. | mm.  |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |      | 4.6  | 0.173 |       | 0.181 |
| B    | 2.5  |      | 2.7  | 0.098 |       | 0.106 |
| D    | 2.5  |      | 2.75 | 0.098 |       | 0.108 |
| E    | 0.45 |      | 0.7  | 0.017 |       | 0.027 |
| F    | 0.75 |      | 1    | 0.030 |       | 0.039 |
| F1   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| F2   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| G    | 4.95 |      | 5.2  | 0.195 |       | 0.204 |
| G1   | 2.4  |      | 2.7  | 0.094 |       | 0.106 |
| H    | 10   |      | 10.4 | 0.393 |       | 0.409 |
| L2   |      | 16   |      |       | 0.630 |       |
| L3   | 28.6 |      | 30.6 | 1.126 |       | 1.204 |
| L4   | 9.8  |      | 10.6 | .0385 |       | 0.417 |
| L5   | 2.9  |      | 3.6  | 0.114 |       | 0.141 |
| L6   | 15.9 |      | 16.4 | 0.626 |       | 0.645 |
| L7   | 9    |      | 9.3  | 0.354 |       | 0.366 |
| Ø    | 3    |      | 3.2  | 0.118 |       | 0.126 |



**Figure 22: Revision History**

| Date        | Revision | Description of Changes |
|-------------|----------|------------------------|
| 14-Jun-2005 | 1        | New release            |
| 19-Jul-2005 | 2        | Complete version       |

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